

### Features

- 6-bit, 0.5 dB LSB, 31.5 dB range
- DC to 40 GHz operation
- Integrated TTL 0/+5V control
- +/- 0.5 dB typical bit error
- Low RMS phase 4.3° @ 20 GHz
- Die size: 1.55 x 0.95 x 0.1 mm
- ESD protection for all controls and bias
- 100% On-wafer DC & RF Tested
- RoHS\* Compliant

### Applications

- Aerospace & Defense
- ISM

### Description

The MAAD-011021 is a wide band 6-bit digital attenuator covering DC to 40 GHz. The attenuation bit-values are 0.5 dB LSB (least significant bit), 1, 2, 4, 8, and 16 dB for a total attenuation of 31.5 dB. Attenuation error is typically less than +/- 0.5 dB, RMS phase error is less than 5 degrees at 20 GHz, and typical insertion loss is 7.1 dB at 15 GHz. Return loss is typically 12 dB across all frequencies and attenuation states.

The attenuator integrates an inverter to allow a single control for series/shunt attenuation. Inverter requires a -5 V supply ( $V_{CC}$ ) and 17 mA typical, logic is 0 V / +5 V.

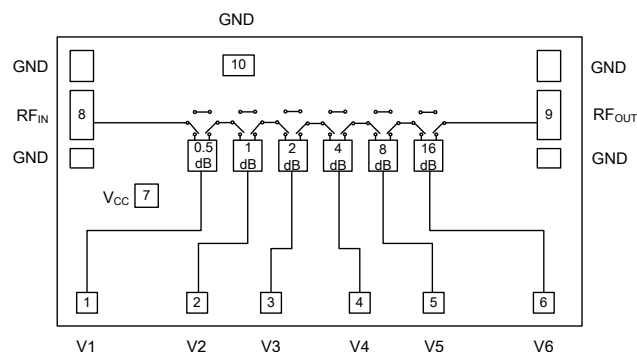
The device is also available in a lead-free 3 mm 16-lead PQFN plastic package; order part number MAAD-011021-TR0500.

### Ordering Information<sup>1</sup>

Part Number	Package
MAAD-011021-0GPDIE	Die in Gel Pack
MAAD-011021-DIESMB	Die on Sample Board

1. All sample boards include 3 loose parts.

### Functional Schematic



### Pad Configuration

Pad #	Pad Name	Function
1	V1	0.5 dB bit control
2	V2	1 dB bit control
3	V3	2 dB bit control
4	V4	4 dB bit control
5	V5	8 dB bit control
6	V6	16 dB bit control
7	$V_{CC}$	-5 V Bias
8	$RF_{IN}$	RF Input
9	$RF_{OUT}$	RF Output
10	GND	RF and DC Ground
11	Pad <sup>2</sup>	Back of die

2. The pad on the backside of the die must be connected to RF, DC and thermal ground.

\* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

**Electrical Specifications:  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = -5\text{ V}$ ,  $Z_0 = 50\ \Omega$  (unless otherwise specified)**

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Insertion Loss	DC - 20 GHz	dB	—	6.4	—
	20 - 40 GHz			8.8	—
	10 GHz			6.0	7.0
	20 GHz			7.0	8.0
	30 GHz			8.0	9.0
Return Loss	DC - 40 GHz	dB	—	15	—
Attenuation Bits	20 GHz	dB	0.3	0.4	0.5
	LSB: 0.5 dB		0.7	0.9	1.0
	Bit 2: 1 dB		1.6	1.75	1.9
	Bit 3: 2 dB		3.6	3.8	4.0
	Bit 4: 4 dB		7.0	8.0	9.0
	Bit 5: 8 dB		16.0	17.4	19.0
Attenuation Error RMS	DC - 20 GHz	dB	—	0.3	—
	20 - 40 GHz			1.2	—
Phase Error RMS	DC - 20 GHz	deg	—	2.6	—
	20 - 40 GHz			7.2	—
Input P0.1dB	DC - 40 GHz	dBm	—	24	—
Input IP3	DC - 40 GHz	dBm	—	38	—
Switching Time	DC - 40 GHz	ns	—	45	—
Control Logic	DC - 40 GHz	V	—	0/+5	—
Control Current	each control bit @ +5 V	mA	—	6	—
Supply Current	DC - 40 GHz	mA	—	17	45

**Absolute Maximum Ratings<sup>3,4</sup>**

Parameter	Absolute Maximum
Input Power	+35 dBm
Operating Voltage	-5 V
Control Voltage	0 / +5 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.

**Handling Procedures**

Please observe the following precautions to avoid damage:

**Static Sensitivity**

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1A devices.

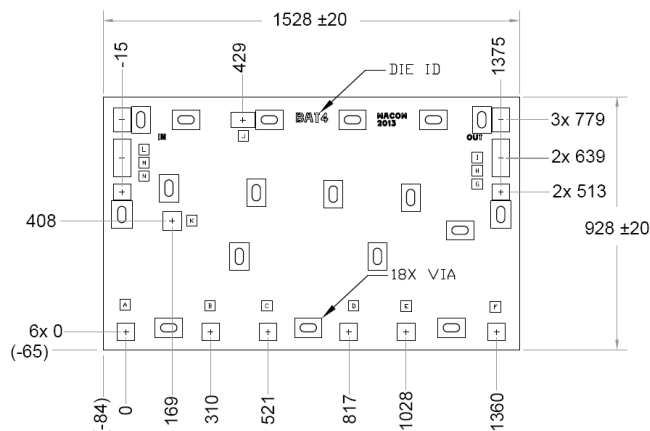
## Truth Table<sup>5,6</sup>

V1 0.5 dB	V2 1 dB	V3 2 dB	V4 4 dB	V5 8 dB	V6 16 dB	State
low	low	low	low	low	low	0 dB
high	low	low	low	low	low	0.5 dB
low	high	low	low	low	low	1 dB
low	low	high	low	low	low	2 dB
low	low	low	high	low	low	4 dB
low	low	low	low	high	low	8 dB
low	low	low	low	low	high	16 dB
high	high	high	high	high	high	31.5 dB

5. high = +5 V @ 5.7 mA, low = 0 V @ 1.0 mA.

6. Any combination of the above states will provide attenuation approximately equal to the sum of the bits selected.

## Die Layout



### Notes:

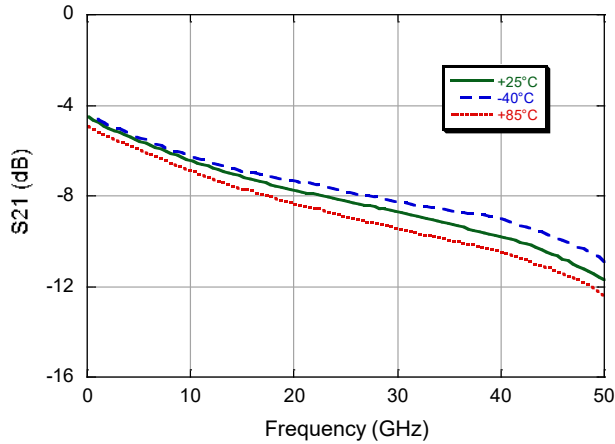
1. All units are in  $\mu\text{m}$ , unless otherwise noted, with a tolerance of  $\pm 5 \mu\text{m}$ .
2. Die thickness is  $100 \pm 10 \mu\text{m}$ .

## Bond Pad Opening Detail

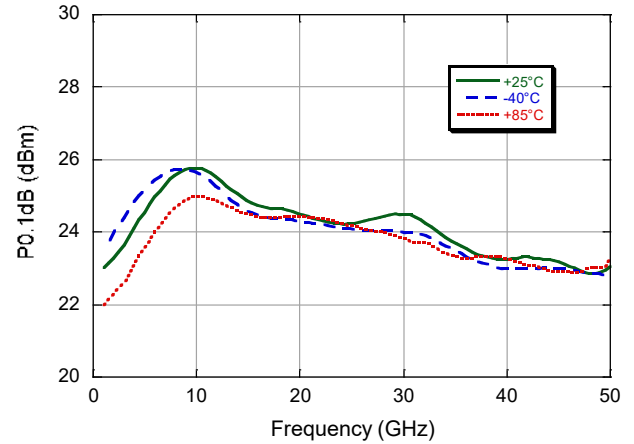
Pad	Size (x) $\mu\text{m}$	Size (y) $\mu\text{m}$
A - F	64	64
G, N	64	59
H, M	64	139
I, L	64	87
J	89	57
K	69	69

Typical Performance Curves

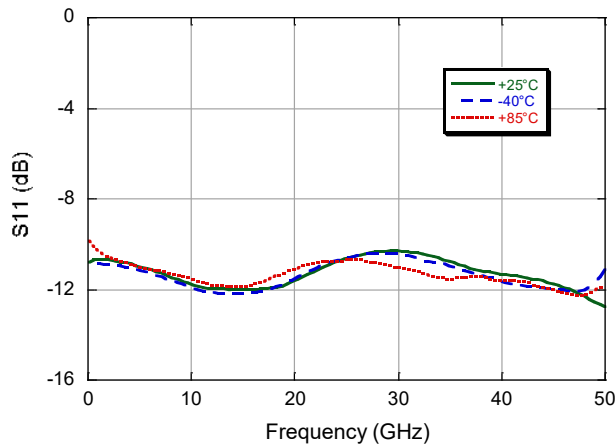
Insertion Loss



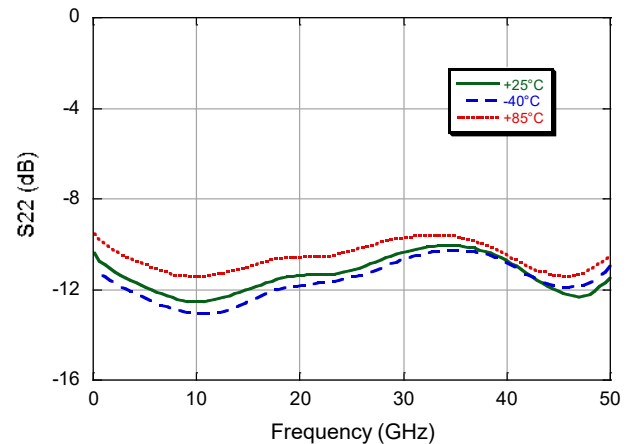
P0.1dB Compression



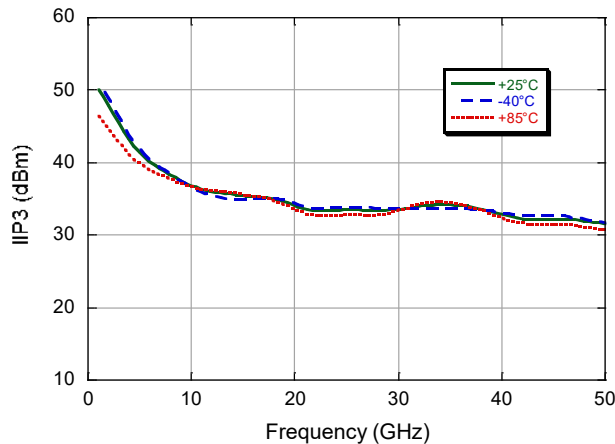
Maximum Input Return Loss (all states)



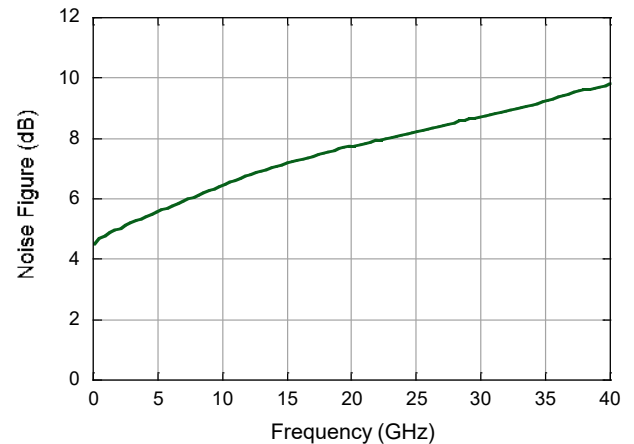
Maximum Output Return Loss (all states)



Input IP3 (reference states)

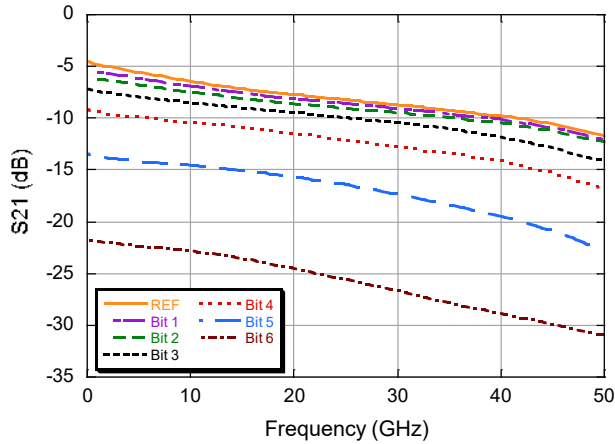


Noise Figure (reference states)

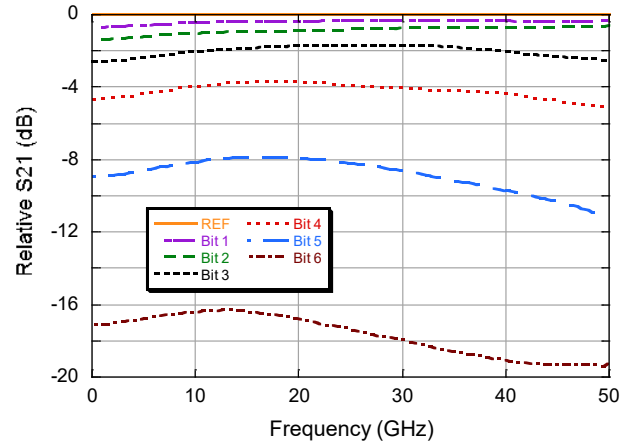


Typical Performance Curves

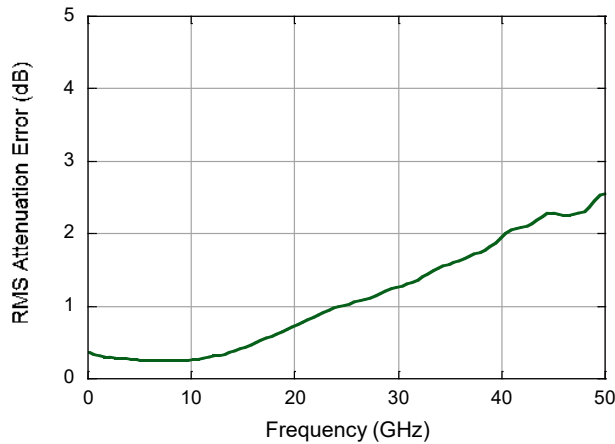
Attenuation



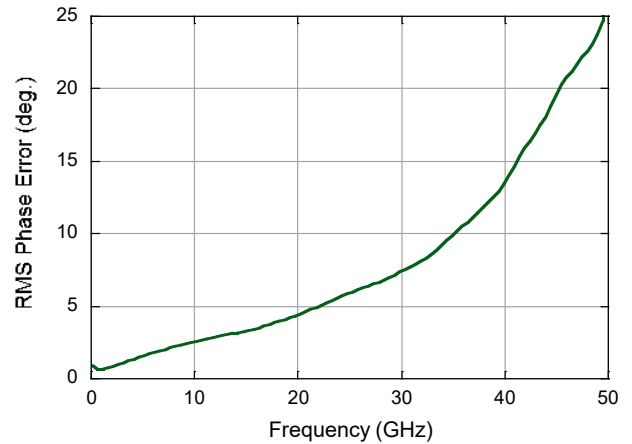
Relative Attenuation



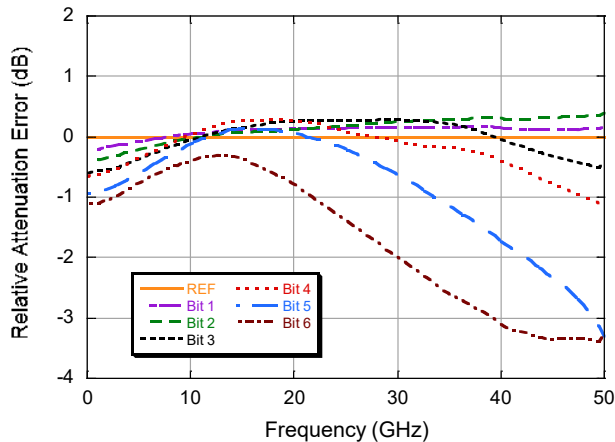
RMS Attenuation Error



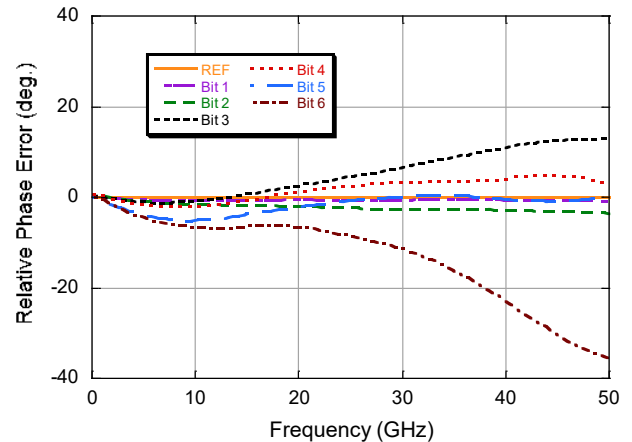
RMS Phase Error



Relative Attenuation Error

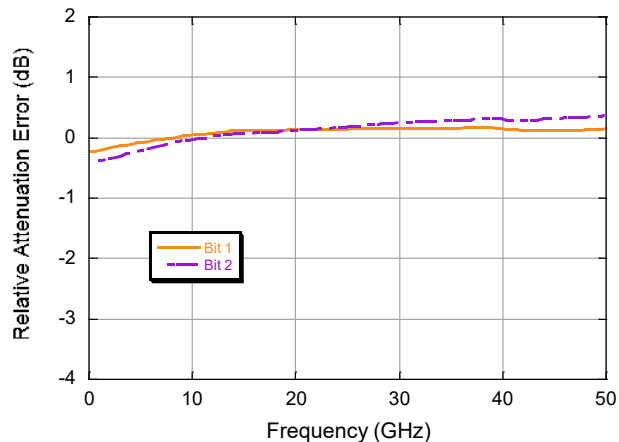


Relative Phase Error

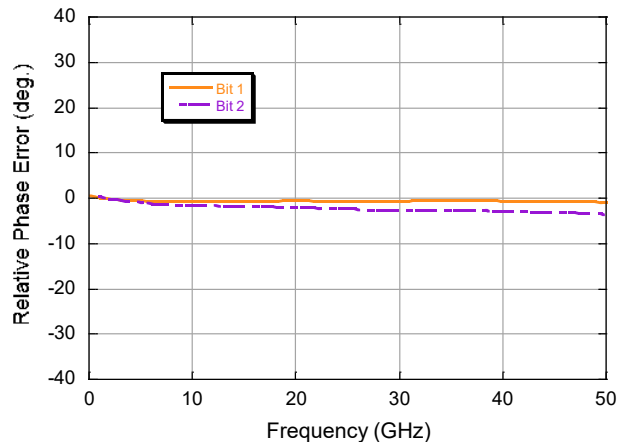


## Typical Performance Curves

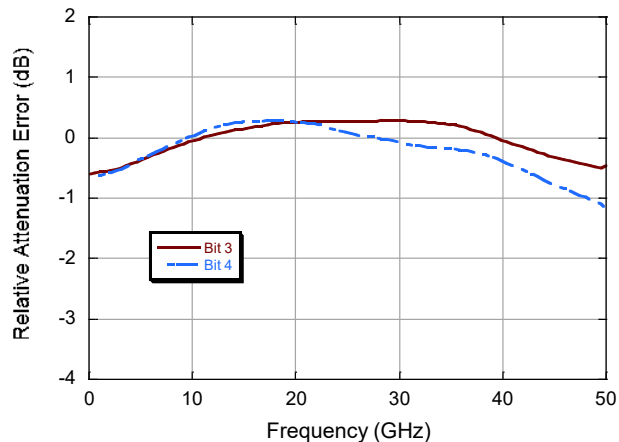
**Relative Attenuation Error (Bit 1, 2)**



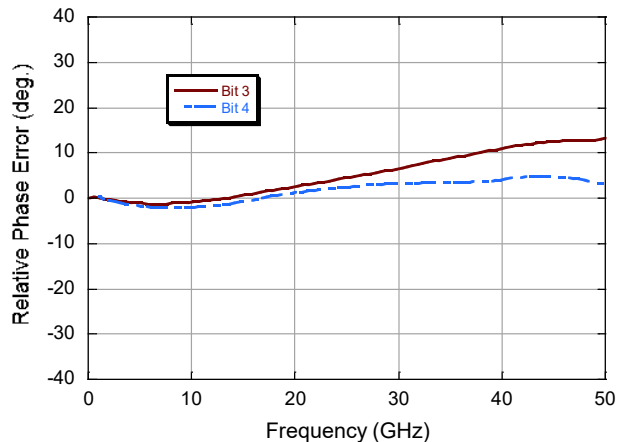
**Relative Phase Error (Bit 1, 2)**



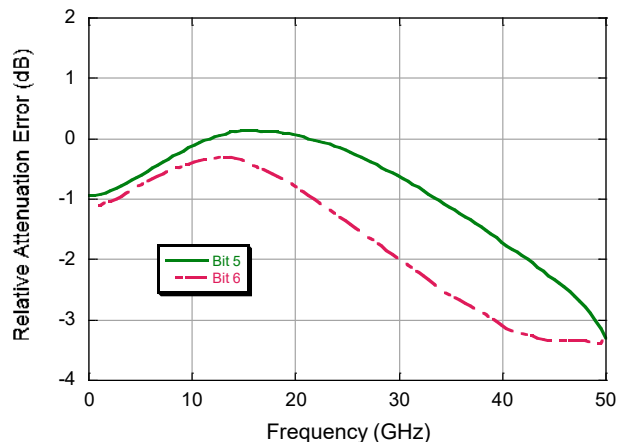
**Relative Attenuation Error (Bit 3, 4)**



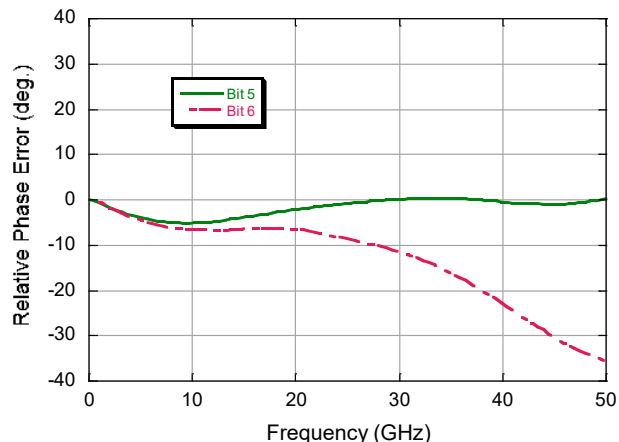
**Relative Phase Error (Bit 3, 4)**



**Relative Attenuation Error (Bit 5, 6)**

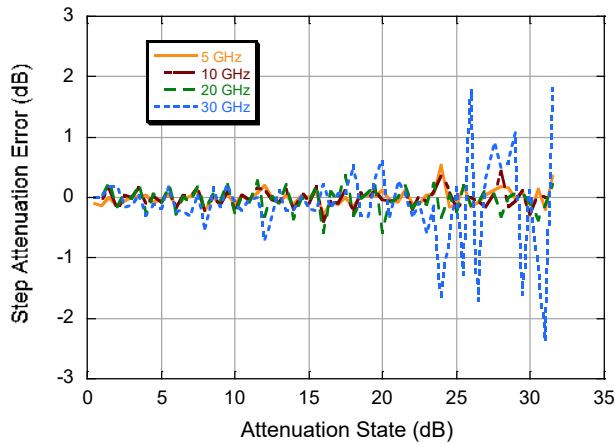


**Relative Phase Error (Bit 5, 6)**

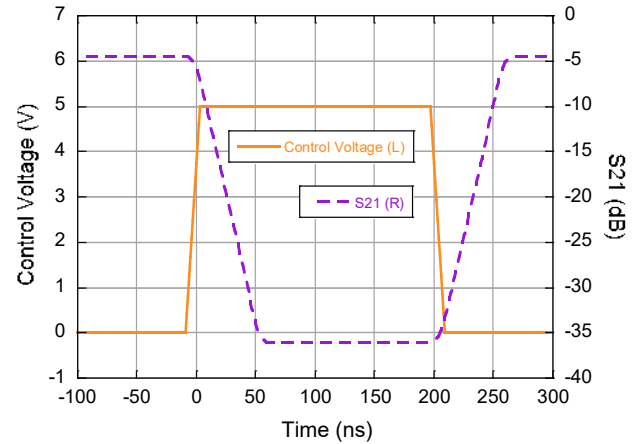


### Typical Performance Curves

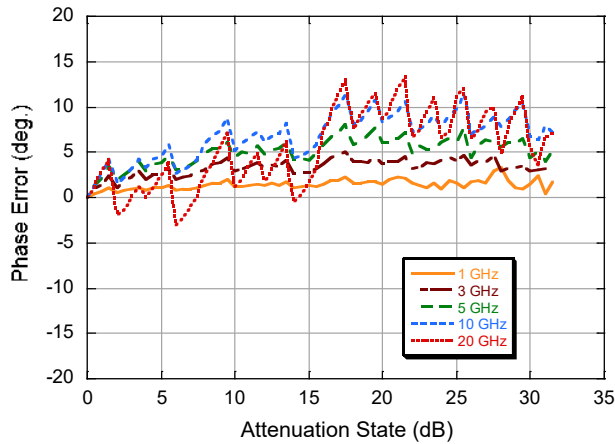
Step Error Between Successive States



Switching Time



Phase Error over Attenuation States



## Applications Section

### Application Information

The MAAD-011021 is designed for extremely wide band and robust attenuation applications. It uses a combination of series and shunt cold channel, multiple-gate FETs to achieve high linearity and accurate attenuation repeatability. We recommend using double bonds at both RF input and output, as well as keeping bondwires as short as possible to ensure higher frequency operation. This part is the most accurate for X-band applications.

The MAAD-011021 has a built in inverter function which allows a single +5 V / 0 V single control for each bit. This is useful if you require very fast switching times and have +5 V / 0 V available.

The MAAD-011021 is DC-coupled at both  $RF_{IN}$  and  $RF_{OUT}$ . If operation at DC is desired, 0  $\Omega$  jumpers (or continuous 50  $\Omega$  RF lines) should be used in series with  $RF_{IN}$  and  $RF_{OUT}$ . Customer should take extra care to ensure that the voltage at both  $RF_{IN}$  and  $RF_{OUT}$  are 0 V; excess voltage can damage the part. If operation at DC is not required, simply use series blocking capacitors.

### Mounting and Bonding Techniques

The Monolithic Circuit is designed for robust and reliable usage. The die features complete passivation on all critical areas as well as a protective BCB die coat.

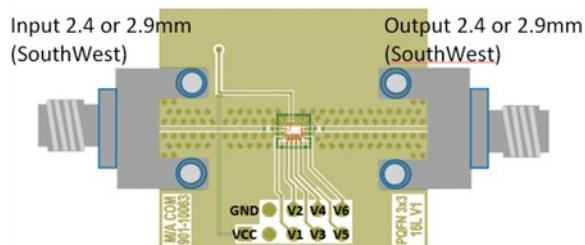
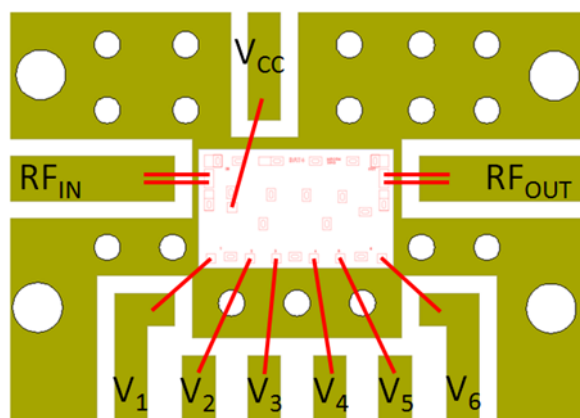
The die should be attached directly to the ground plane with silver conductive epoxy for best results.

A true 50  $\Omega$  microstrip or co-planar waveguide is recommended for bringing RF to and from the die as shown in the demonstration board below. This board uses 0.200 mm (8 mils) Rogers 4350 as the top dielectric layer.

Alternatively one can mount the die directly to the ground plane and launch with microstrip substrates in either alumina or Rogers to the same level as the top of the die, allowing for shorter bond wires.

The RF input and output pads are DC coupled. Blocking capacitors are required if there is a DC potential on either port.

### PCB Layout



Sample board size above is 28 x 25 mm



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